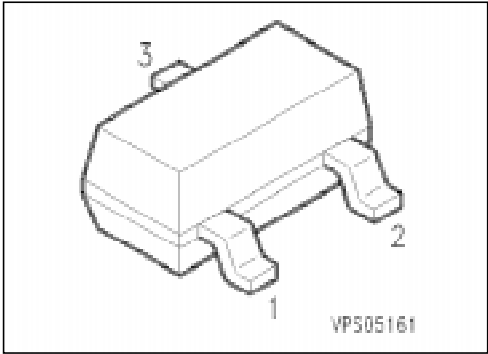


PNP Silicon AF Transistors

BCW 61
BCX 71

- For AF input stages and driver applications
- High current gain
- Low collector-emitter saturation voltage
- Low noise between 30 Hz and 15 kHz
- Complementary types: BCW 60, BCX 70 (NPN)



Type	Marking	Ordering Code (tape and reel)	Pin Configuration			Package ¹⁾
			1	2	3	
BCW 61 A	BAs	Q62702-C452	B	E	C	SOT-23
BCW 61 B	BBs	Q62702-C1585				
BCW 61 C	BCs	Q62702-C1478				
BCW 61 D	BDs	Q62702-C1556				
BCW 61 FF	BFs	Q62702-C1890				
BCW 61 FN	BNs	Q62702-C1891				
BCX 71G	BGs	Q62702-C1482				
BCX 71H	BHs	Q62702-C1586				
BCX 71J	BJs	Q62702-C1554				
BCX 71 K	BKs	Q62702-C1654				

¹⁾ For detailed information see chapter Package Outlines.

Maximum Ratings

Parameter	Symbol	Values			Unit
		BCW 61	BCW 61 FF	BCX 71	
Collector-emitter voltage	V_{CE0}	32	32	45	V
Collector-base voltage	V_{CB0}	32	32	45	
Emitter-base voltage	V_{EB0}	5			
Collector current	I_C	100			mA
Peak collector current	I_{CM}	200			
Peak base current	I_{BM}	200			
Total power dissipation, $T_s = 71\text{ °C}$	P_{tot}	330			mW
Junction temperature	T_j	150			°C
Storage temperature range	T_{stg}	− 65 ... + 150			

Thermal Resistance

Junction - ambient ¹⁾	$R_{th JA}$	≤ 310	K/W
Junction - soldering point	$R_{th JS}$	≤ 240	

¹⁾ Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm² Cu.

Electrical Characteristics

at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

DC characteristics

Collector-emitter breakdown voltage $I_C = 10\text{ mA}$	$V_{(BR)CE0}$	32 45	— —	— —	V
Collector-base breakdown voltage $I_C = 10\text{ }\mu\text{A}$	$V_{(BR)CB0}$	32 45	— —	— —	
Emitter-base breakdown voltage $I_E = 1\text{ }\mu\text{A}$	$V_{(BR)EB0}$	5	—	—	
Collector cutoff current $V_{CB} = 32\text{ V}$	I_{CB0}	—	—	20	nA
$V_{CB} = 45\text{ V}$		—	—	20	nA
$V_{CB} = 32\text{ V}, T_A = 150\text{ }^{\circ}\text{C}$		—	—	20	μA
$V_{CB} = 45\text{ V}, T_A = 150\text{ }^{\circ}\text{C}$		—	—	20	μA
Emitter cutoff current $V_{EB} = 4\text{ V}$	I_{EB0}	—	—	20	nA
DC current gain ¹⁾ $I_C = 10\text{ }\mu\text{A}, V_{CE} = 5\text{ V}$	h_{FE}				—
BCW 61 A, BCX 71 G		20	140	—	
BCW 61 B, BCX 71 H		30	200	—	
BCW 61 FF, BCW 61 C, BCX 71 J		40	300	—	
BCW 61 FN, BCW 61 D, BCX 71 K		100	460	—	
$I_C = 2\text{ mA}, V_{CE} = 5\text{ V}$					
BCW 61 A, BCX 71 G		120	170	220	
BCW 61 B, BCX 71 H		180	250	310	
BCW 61 FF, BCW 61 C, BCX 71 J		250	350	460	
BCW 61 FN, BCW 61 D, BCX 71 K		380	500	630	
$I_C = 50\text{ mA}, V_{CE} = 1\text{ V}$					
BCW 61 A, BCX 71 G		60	—	—	
BCW 61 B, BCX 71 H		80	—	—	
BCW 61 FF, BCW 61 C, BCX 71 J		100	—	—	
BCW 61 FN, BCW 61 D, BCX 71 K		110	—	—	

¹⁾ Pulse test: $t \leq 300\text{ }\mu\text{s}$, $D \leq 2\text{ }\%$.

Electrical Characteristics

at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

DC characteristics

Collector-emitter saturation voltage ¹⁾ $I_C = 10\text{ mA}$, $I_B = 0.25\text{ mA}$ $I_C = 50\text{ mA}$, $I_B = 1.25\text{ mA}$	V_{CEsat}	— —	0.12 0.20	0.25 0.55	V
Base-emitter saturation voltage ¹⁾ $I_C = 10\text{ mA}$, $I_B = 0.25\text{ mA}$ $I_C = 50\text{ mA}$, $I_B = 1.25\text{ mA}$	V_{BEsat}	— —	0.70 0.83	0.85 1.05	
Base-emitter voltage ¹⁾ $I_C = 10\text{ }\mu\text{A}$, $V_{CE} = 5\text{ V}$ $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$ $I_C = 50\text{ mA}$, $V_{CE} = 1\text{ V}$	$V_{BE(on)}$	— 0.55 —	0.52 0.65 0.78	— 0.75 —	

AC characteristics

Transition frequency $I_C = 20\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 100\text{ MHz}$	f_T	—	250	—	MHz
Output capacitance $V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$	C_{obo}	—	3	—	pF
Input capacitance $V_{CB} = 0.5\text{ V}$, $f = 1\text{ MHz}$	C_{ibo}	—	8	—	
Short-circuit input impedance $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BCW 61 A, BCX 71 G BCW 61 B, BCX 71 H BCW 61 FF, BCW 61 C, BCX 71 J BCW 61 FN, BCW 61 D, BCX 71 K	h_{11e}	— — — —	2.7 3.6 4.5 7.5	— — — —	$k\Omega$
Open-circuit reverse voltage transfer ratio $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BCW 61 A, BCX 71 G BCW 61 B, BCX 71 H BCW 61 FF, BCW 61 C, BCX 71 J BCW 61 FN, BCW 61 D, BCX 71 K	h_{12e}	— — —	1.5 2.0 2.0 3.0	— — —	

¹⁾ Pulse test: $t \leq 300\text{ }\mu\text{s}$, $D \leq 2\text{ }\%$.

Electrical Characteristics

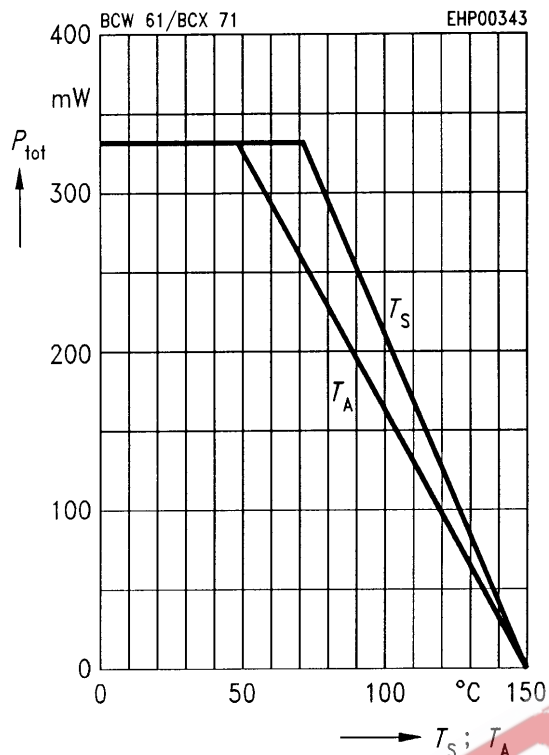
at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

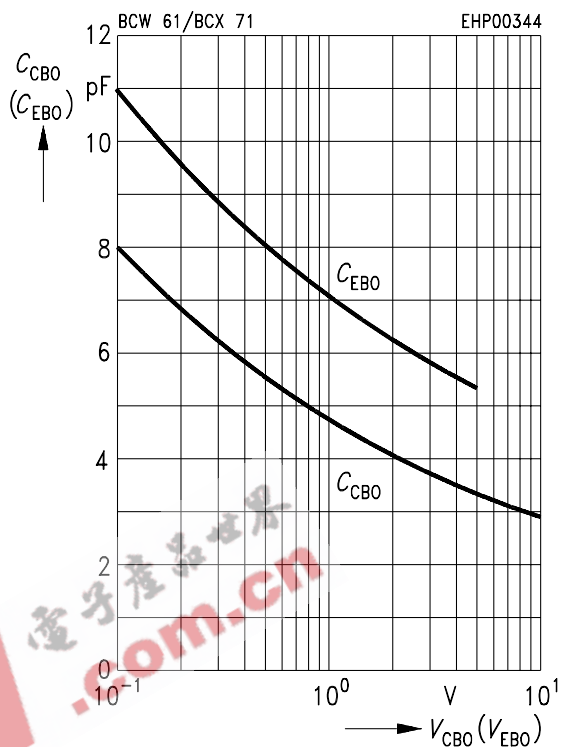
AC characteristics

Short-circuit forward current transfer ratio $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BCW 61 A, BCX 71 G BCW 61 B, BCX 71 H BCW 61 FF, BCW 61 C, BCX 71 J BCW 61 FN, BCW 61 D, BCX 71 K	h_{21e}	— — — —	200 260 330 520	— — — —	—
Open-circuit output admittance $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BCW 61 A, BCX 71 G BCW 61 B, BCX 71 H BCW 61 FF, BCW 61 C, BCX 71 J BCW 61 FN, BCW 61 D, BCX 71 K	h_{22e}	— — — —	18 24 30 50	— — — —	μS
Noise figure $I_C = 0.2\text{ mA}$, $V_{CE} = 5\text{ V}$, $R_S = 2\text{ k}\Omega$ $f = 1\text{ kHz}$, $\Delta f = 200\text{ Hz}$ BCW 61 A to BCX 71 K BCW 61 FF, BCW 61 FN	F	— —	2 1	— 2	dB
Equivalent noise voltage $I_C = 0.2\text{ mA}$, $V_{CE} = 5\text{ V}$, $R_S = 2\text{ k}\Omega$ $f = 10\text{ Hz} \dots 50\text{ Hz}$ BCW 61 FF, BCW 61 FN	V_n	—	—	0.11	μV

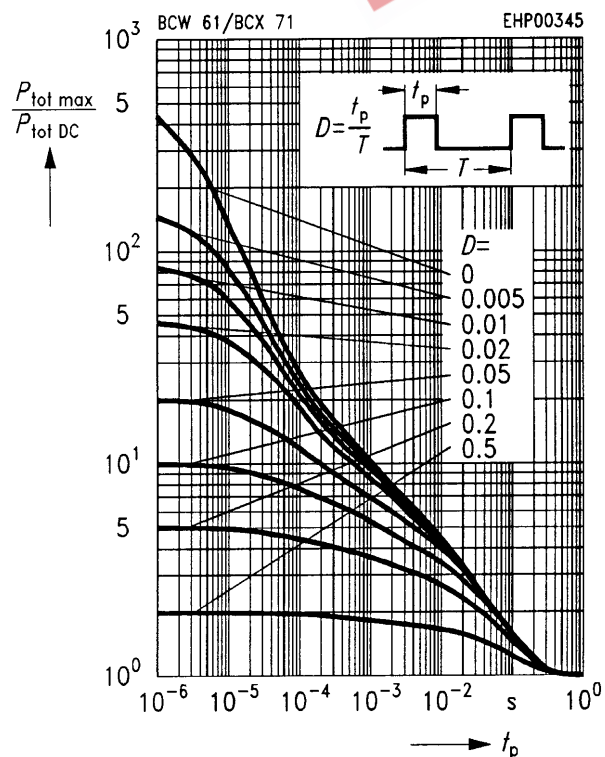
Total power dissipation $P_{\text{tot}} = f(T_A^*; T_S)$
* Package mounted on epoxy



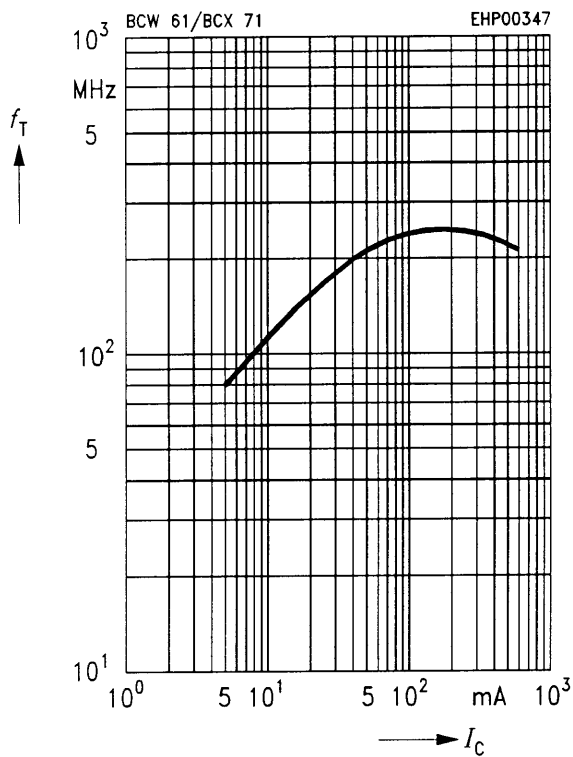
Collector-base capacitance $C_{CB0} = f(V_{CB0})$
Emitter-base capacitance $C_{EB0} = f(V_{EB0})$



Permissible pulse load $P_{\text{tot max}}/P_{\text{tot DC}} = f(t_p)$



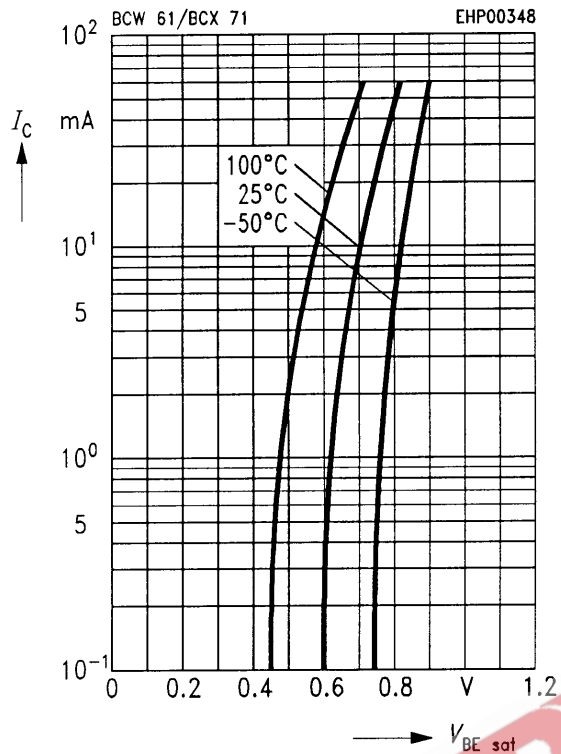
Transition frequency $f_T = f(I_C)$
 $V_{CE} = 5 \text{ V}$



Base-emitter saturation voltage

$$I_C = f(V_{BEsat})$$

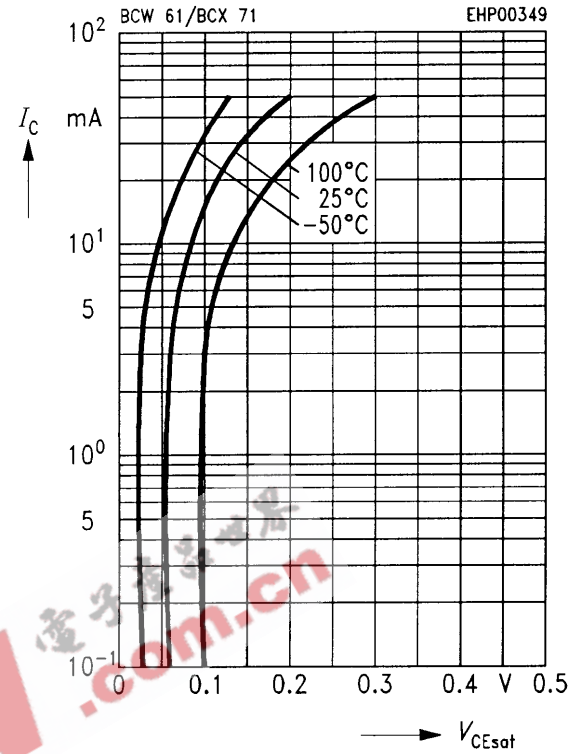
$$h_{FE} = 40$$



Collector-emitter saturation voltage

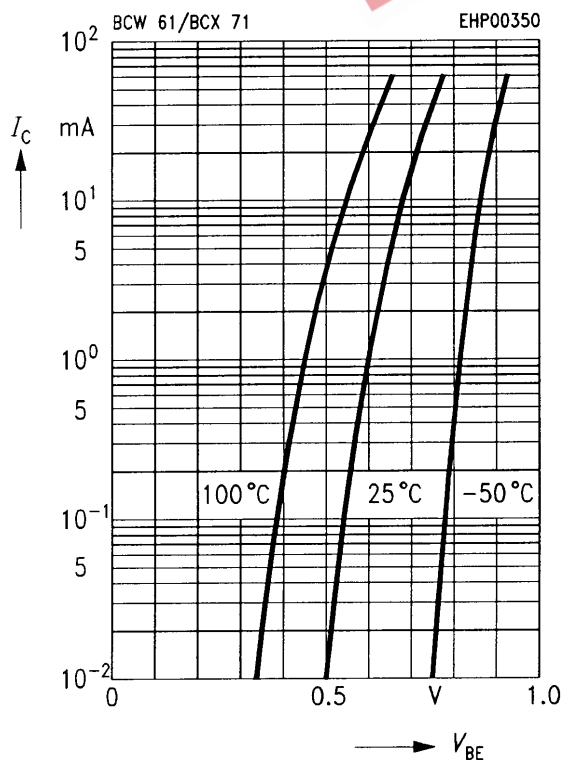
$$I_C = f(V_{CEsat})$$

$$h_{FE} = 40$$



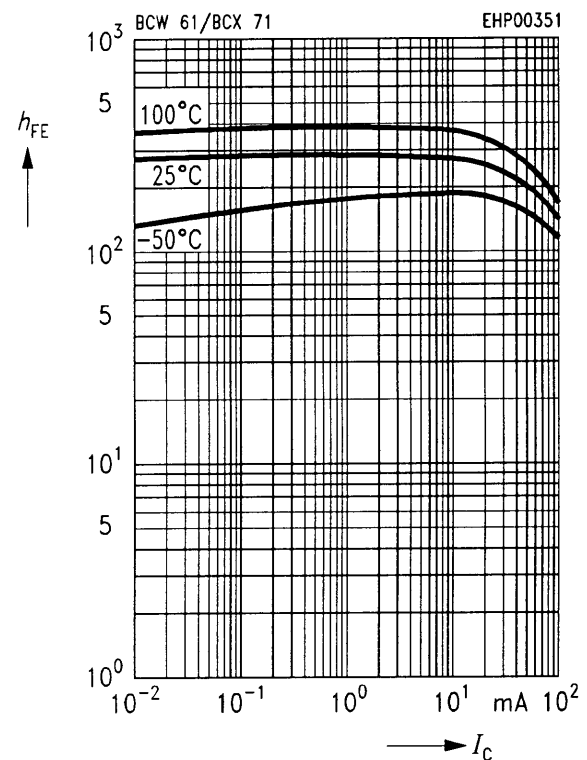
Collector current $I_C = f(V_{BE})$

$$V_{CE} = 5 \text{ V}$$

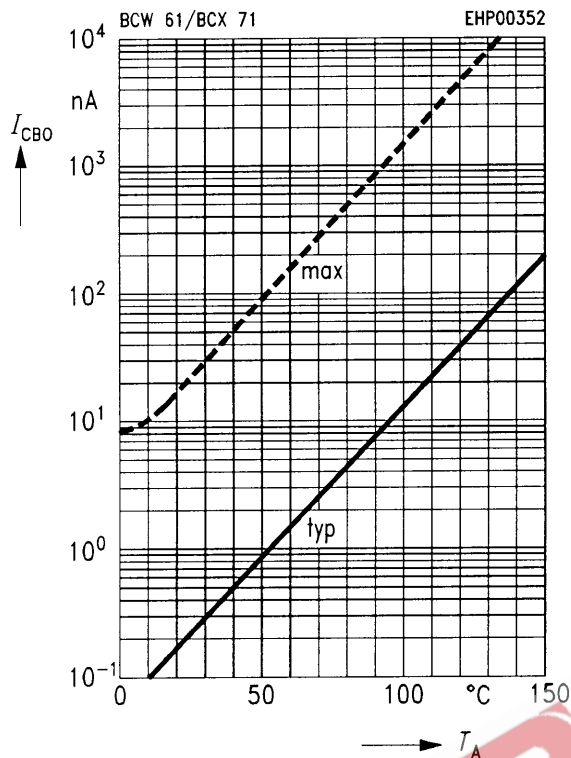


DC current gain $h_{FE} = f(I_C)$

$$V_{CE} = 5 \text{ V}$$

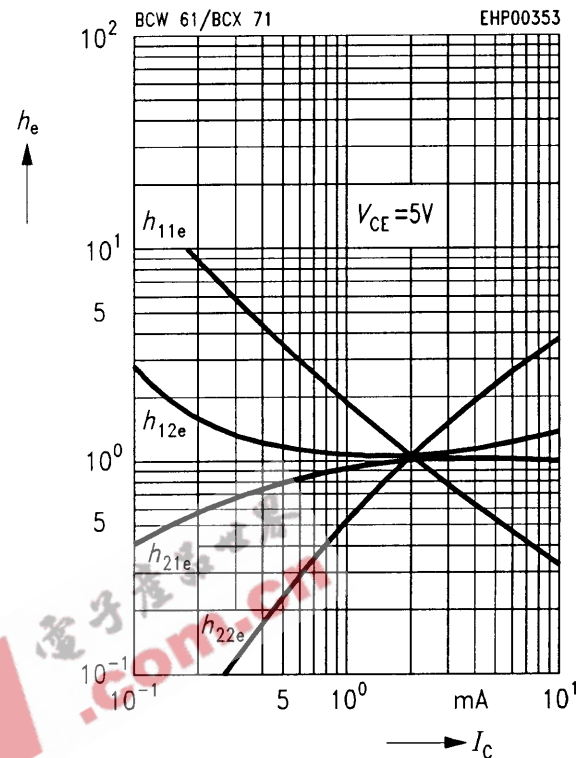


Collector cutoff current $I_{CB0} = f(T_A)$



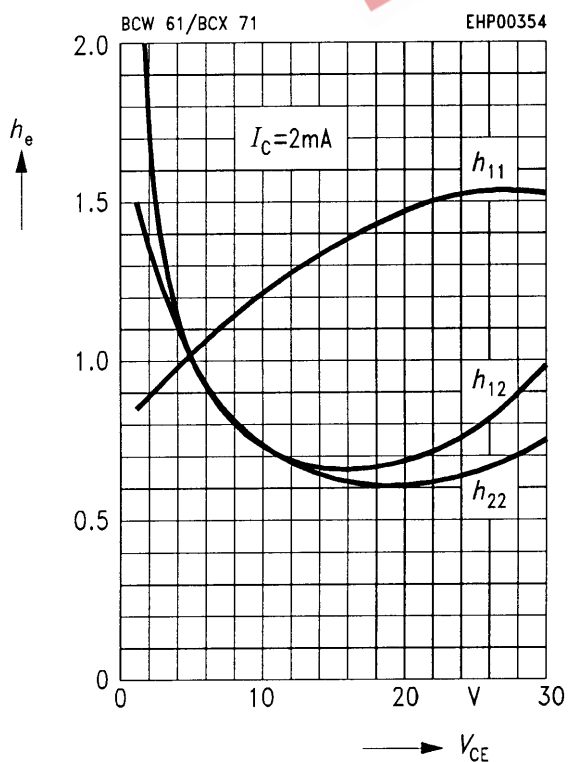
h parameter $h_e = f(I_C)$

$V_{CE} = 5\text{ V}$



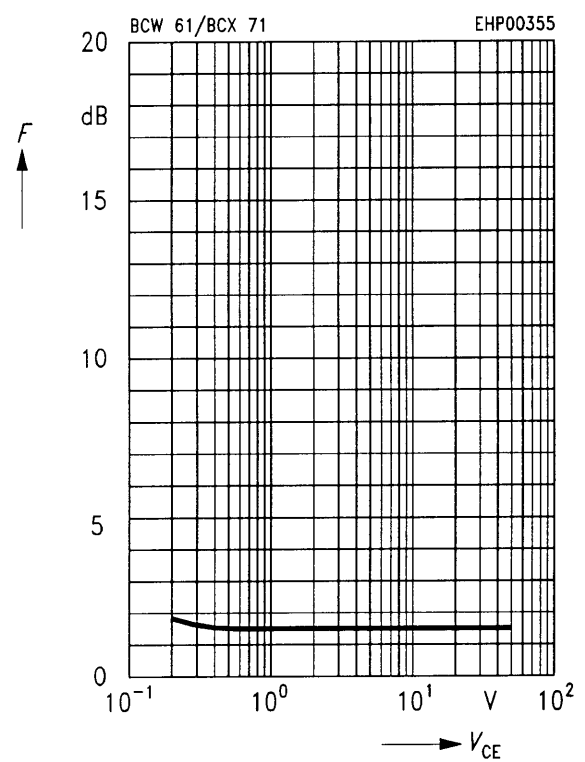
h parameter $h_e = f(V_{CE})$

$I_C = 2\text{ mA}$



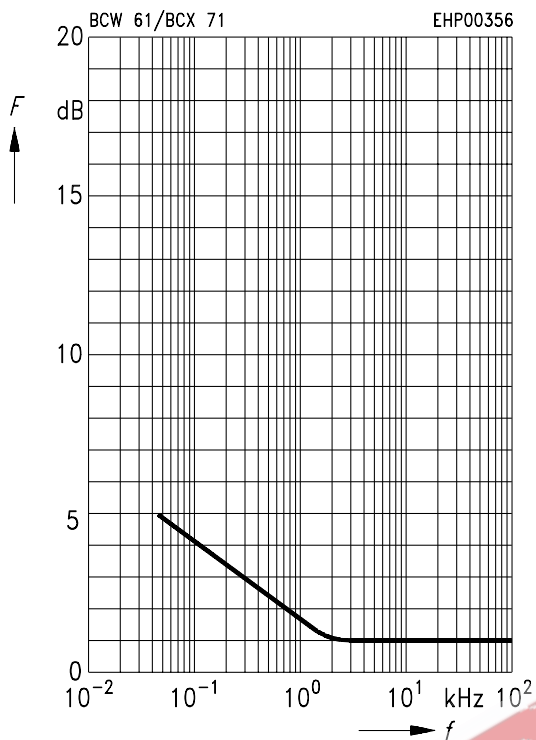
Noise figure $F = f(V_{CE})$

$I_C = 0.2\text{ mA}$, $R_S = 2\text{ k}\Omega$, $f = 1\text{ kHz}$



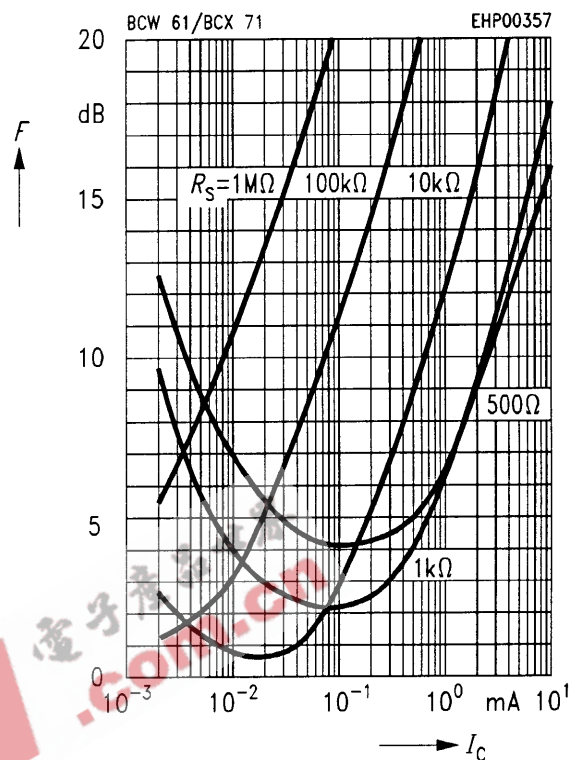
Noise figure $F = f(f)$

$I_C = 0.2 \text{ mA}$, $R_S = 2 \text{ k}\Omega$, $V_{CE} = 5 \text{ V}$



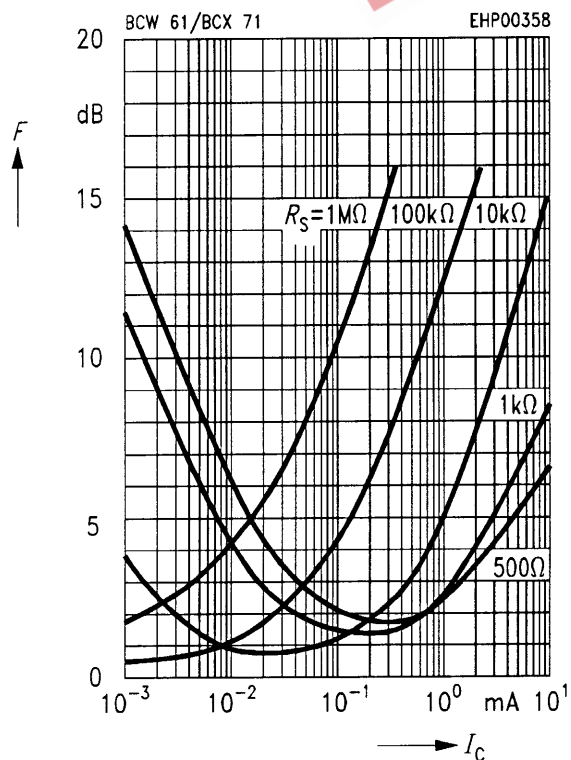
Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 120 \text{ Hz}$



Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 1 \text{ kHz}$



Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 10 \text{ kHz}$

